

IPT65R105G7

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Data Sheet

RFO

A new SMD package using Kelvin source concept

Manufacturers	Infineon Technologies Corporation	
Package/Case		
Product Type		
RoHS		
Lifecycle		Images are for reference only

Please submit RFQ for IPT65R105G7 or Email to us: sales@ovaga.com We will contact you in 12 hours.

General Description

The CoolMOSTM C7 Gold superjunction MOSFET series (G7) for the first time brings together the benefits of the improved 650V CoolMOSTM C7 Gold technology, 4pin Kelvin source capability and the improved thermal properties of the TOLL package to enable an SMD solution for high current hard switching topologies such as power factor correction (PFC) up to 3kW.

Features

Gives best-in-class FOM R DS(on)*E oss and R DS(on)*Q G

Enables best-in-class R DS(on) in smallest footprint

Inbuilt 4th pin Kelvin source configuration and low parasitic source inductance (~1nH)

Is MSL1 compliant, total Pb-free, has easy visual inspection grooved leads

Enables improved thermal performance R th

FOM R DS(on)xQ G is 14% better than previous 650V CoolMOS™ C7 enabling faster switching leading to higher efficiency

Power density trough BIC $33m\Omega$ in 115mm 2 TOLL footprint

Reducing parasitic source inductance by Kelvin source improves efficiency switching and ease-of-use

TOLL package is easy to use and has the highest quality standards

Improved thermals enable SMD TOLL package to be used in higher current designs than has been previously possible

Related Products



IPB054N08N3G

Infineon Technologies Corporation TO-263



<u>IPD040N03LG</u>

Infineon Technologies Corporation TO-252



IPD25CN10NG

Infineon Technologies Corporation TO-252



IPAW60R180P7S

Infineon Technologies Corporation









IPA60R180C7

Infineon Technologies Corporation TO-220F

<u>IPP075N15N3</u>

Infineon Technologies Corporation

IPB65R190CFDA

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IPN70R2K0P7S

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